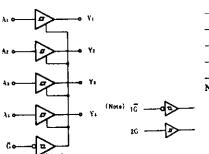
■BLOCK DIAGRAM (½)

INFUNCTION TABLE

PIN ARRANGEMENT



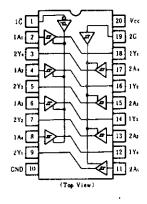
Inputs			Output	
1 <u>G</u>	2G	A	Y	
Н	L	×	Z	
L	Н	Н	Н	
L	Н	L.	L	

H; high level, Note) L; low level,

X; irrelevant

Z; off (high-impedance) state

of a 3-state output



ELECTRICAL CHARACTERISTICS ($Ta = -20 \sim +75^{\circ}C$)

	Item	Symbol	Test Conditio	ns	min	typ*	max	Unit	
		VIH			2.0	-		V	
Input voltage		VIL			_	_	0.8	V	
Hysteresis		$V_{T}^{+}-V_{T}^{-}$	Vcc=4.75V		0.2	0.4		V	
Output voltage	1/	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.8 \text{V}$, <i>Ion</i> = − 3mA	2.4			v		
		$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.5 \text{V}, I_{OH} = -15 \text{mA}$		2.0		-	· · · · · ·		
	Vot Vcc=	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V},$ $V_{IL} = 0.8 \text{V}$	IoL = 12mA		_	0.4	v		
			IoL = 24mA	-		0.5			
Output current	Іогн	$V_{CC} = 5.25 \text{V}, V_{IH} = 2 \text{V},$	$V_0 = 2.7V$	-		20	μА		
	Iozi	$V_{IL}=0.8V$	Vo=0.4V	_		- 20			
Input current		Iгн	$V_{CC} = 5.25 \text{V}, V_I = 2.7 \text{V}$		_		20	μA	
		In	$V_{CC} = 5.25 \text{V}, V_I = 0.4 \text{V}$		_	-	-0.2	mA	
		Iı .	$V_{CC} = 5.25 \text{V}, V_{I} = 7 \text{V}$		_		0.1	mA	
Short-circui	t output current	los	V _{CC} =5.25V		-40	_	-225	mA	
Supply Current** Outputs high Outputs low	·						13	23	
	Outputs low	I cc	Vcc = 5.25V			27	46	mA	
	All outputs disabled	1			_	32	54		
Input clamp		Vik	$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{m}.$	A		_	-1.5	V	

^{*} V_{CC}=5V, Ta=25°C

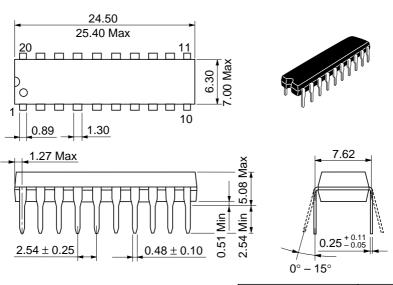
ESWITCHING CHARACTERISTICS ($V_{CC} = 5V$, $T_a = 25^{\circ}C$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Propagation delay time	tplн		_	12	18	ns ns
	tphl.	$C_L = 45 \text{pF}, R_L = 667 \Omega$	_	12	18	
Output enable time	!ZL		_	20	30	ns
	tzn		_	15	23	ns
Output disable time	tLZ	$C_L = 5 \text{pF}, R_L = 667 \Omega$	_	15	25	ns
	tHZ		_	10	18	ns

Refer to Test Circuit and Waveform of the Common Item

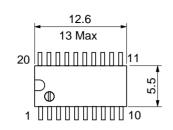
^{**} ICC is measured with all outputs open.

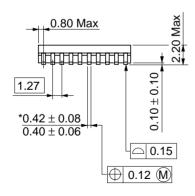
Unit: mm

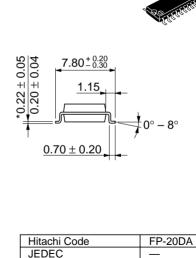


Hitachi Code	DP-20N
JEDEC	_
EIAJ	Conforms
Weight (reference value)	1.26 g

Unit: mm







Weight (reference value)

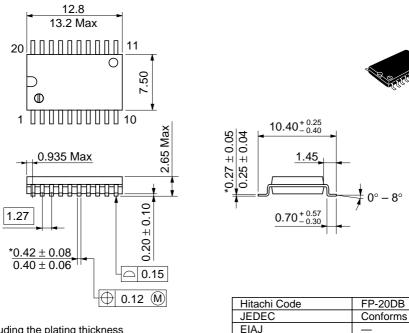
Conforms

0.31 g

EIAJ

*Dimension including the plating thickness
Base material dimension

Unit: mm



Weight (reference value)

0.52 g

*Dimension including the plating thickness
Base material dimension

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